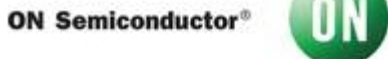
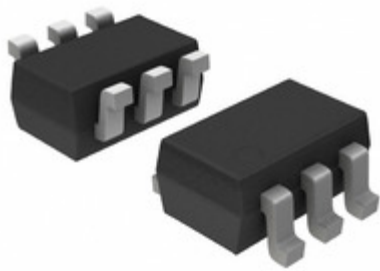











|   |                                |  |
|---|--------------------------------|--|
|  | <b>NTJD4152PT1G</b>            |  |
|   | <b>Hersteller-Teilenummer:</b> | NTJD4152PT1G   |
|  | <b>Hersteller / Marke:</b>     | AMI Semiconductor / ON Semiconductor   |
|   | <b>Teil der Beschreibung:</b>  | MOSFET 2P-CH 20V 0.88A SOT-363   |
| <p>Image may be representation.<br/>See specs for product details.</p>            | <b>Datenblätter:</b>           |  <a href="#">NTJD4152PT1G.pdf</a> |
|   | <b>RoHs Status:</b>            | Bleifrei / RoHS-konform  |
|   | <b>Lagerzustand:</b>           | New original, 127924 pcs Stock Available.  |
|   | <b>Lieferrn von:</b>           | Hong Kong  |
|   | <b>Versandweg:</b>             | DHL/Fedex/TNT/UPS/EMS  |

### Spezifikationen

|   |  |
|---|--|
| Teilenummer                                     | NTJD4152PT1G                                     |
| Hersteller                                      | AMI Semiconductor / ON Semiconductor             |
| Beschreibung                                    | MOSFET 2P-CH 20V 0.88A SOT-363                   |
| Kategorie                                       | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus                                      | 127924 pcs Stock                                 |
| Serie   | -  |
| Betriebstemperatur                              | -55°C ~ 150°C (TJ)                               |
| Befestigungsart                                 | Surface Mount                                    |
| Leistung - max                                  | 272mW  |
| Verpackung / Gehäuse                            | 6-TSSOP, SC-88, SOT-363                          |
| Supplier Device-Gehäuse                         | SC-88/SC70-6/SOT-363                             |
| Typ FET   | 2 P-Channel (Dual)                               |
| FET-Merkmal                                     | Logic Level Gate                                 |
| Drain-Source-Spannung (Vdss)                    | 20V  |
| Strom - Ununterbrochener Abfluss (Id) bei 25 °C | 880mA  |
| Rds On (Max) @ Id, Vgs                          | 260 mOhm @ 880mA, 4.5V                           |
| VGS (th) (Max) @ Id                             | 1.2V @ 250µA                                     |
| Gate Charge (Qg) (Max) @ Vgs                    | 2.2nC @ 4.5V                                     |
| Eingabekapazität (Ciss) (Max) @ Vds             | 155pF @ 20V                                      |
| Verpackung                                      | Tape & Reel (TR)                                 |


















NTJD4152PT1G ist neu im Original, Suche NTJD4152PT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTJD4152PT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTJD4152PT1G: Info@Y-IC.com

Sie können auch interessiert sein:

|   |   |   |  |
|---|---|---|--|
|  <p><b>NTJD4152PT2G</b><br/>AMI Semiconductor / ON Semiconductor<br/>MOSFET 2P-CH 20V 0.88A SC88-6</p> |  <p><b>NTJD4105CT4</b><br/>AMI Semiconductor / ON Semiconductor<br/>MOSFET N/P-CH 20V/8V SOT-363</p>   |  <p><b>NTJD4105CT2</b><br/>AMI Semiconductor / ON Semiconductor<br/>MOSFET N/P-CH 20V/8V SOT-363</p>  |  <p><b>NTJD4105CT2G</b><br/>AMI Semiconductor / ON Semiconductor<br/>MOSFET N/P-CH 20V/8V SOT-363</p>   |
|  <p><b>NTJD4158CT2G</b><br/>AMI Semiconductor / ON Semiconductor<br/>MOSFET N/P-CH 30V/20V SC88-6</p>  |  <p><b>NTJD4152PT1</b><br/>AMI Semiconductor / ON Semiconductor<br/>MOSFET 2P-CH 20V 0.88A SOT-363</p> |  <p><b>NTJD4105CT4G</b><br/>AMI Semiconductor / ON Semiconductor<br/>MOSFET N/P-CH 20V/8V SOT-363</p> |  <p><b>NTJD4401NT1G</b><br/>AMI Semiconductor / ON Semiconductor<br/>MOSFET 2N-CH 20V 0.63A SOT-363</p> |

### heiße Teile

Mehr

|  |   |   |  |  |
|--|---|---|--|--|
|  1808CC272KATME     |  AK2004PCI       |  ATXMEGA32A4-AU    |  BC858BDW1T1G  |  BCM4355MKWBG   |
|  IP-242-CW          |  IRU3038CFTR     |  LBN150B02-7       |  LC1207CC3TR33 |  LL1608-FHL27NJ |
|  LSP0600AJR-S       |  LT3744IUHE#PBF  |  MAX16910DATA9/V+T |  MM3244ANRE    |  MMBT5089LT1G   |
|  MX29F040CQI-70G    |  MXD1817UR31-T   |  NTJD1155LT1G      |  NTJD2152PT1   |  NTJD2152PT1G   |
|  NTJD3115PT1G       |  NTJD3158CT1G    |  NTJD3158CT2G      |  NTJD4001NT1G  |  NTJD4001NT2G   |
|  NTJD4105CT1G       |  NTJD4105CT2G    |  NTJD4152PT1       |  NTJD4158CT1G  |  NTJD4158CT2G   |
|  NTJD4401NT1        |  NTJD4401NT1G    |  NTJD4401NT2       |  NTJD5121NT1G  |  NTJD5121NT2G   |
|  NTJS3151PT1G       |  NTJS3157NT1G    |  NTJS4151PT1G      |  NTJS4160NT1G  |  NTJS4405NT1G   |
|  NTJS4405NT4G       |  NTJS4405UT1     |  PCM2902E          |  PQ025EZ1H     |  Q1257Q6008RH4  |
|  S-80948CNMC-G9JT2G |  SQ3461EV-T1-GE3 |  TC2117-3.0VDBTR   |  TD62706PG     |  VI-J00CY       |

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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